

Small Signal Switching Diode

Features

- Silicon Epitaxial Planar Diode
- Low forward voltage drop
- High forward current capability
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



94 9367

Applications

- High speed switch and general purpose use in computer and industrial applications

Mechanical Data

Case: DO35 Glass case

Weight: approx. 125 mg

Cathode Band Color: black

Packaging Codes/Options:

TR/10 k per 13" reel (52 mm tape), 50 k/box

TAP/10 k per Ammpack (52 mm tape), 50 k/box

Parts Table

| Part | Ordering code | Type Marking | Remarks |
|-------|-----------------------|--------------|-----------------------|
| BAW27 | BAW27-TR or BAW27-TAP | BAW27 | Tape and Reel/Ammpack |

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

| Parameter | Test condition | Symbol | Value | Unit |
|---------------------------------|--|-----------|-------|------|
| Repetitive peak reverse voltage | | V_{RRM} | 75 | V |
| Reverse voltage | | V_R | 60 | V |
| Peak forward surge current | $t_p = 1\text{ }\mu\text{s}$ | I_{FSM} | 4 | A |
| Forward continuous current | | I_F | 600 | mA |
| Average forward current | $V_R = 0$ | I_{FAV} | 300 | mA |
| Power dissipation | $l = 4\text{ mm}, T_L = 45\text{ }^{\circ}\text{C}$ | P_{tot} | 440 | mW |
| | $l = 4\text{ mm}, T_L \leq 25\text{ }^{\circ}\text{C}$ | P_{tot} | 500 | mW |

Thermal Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

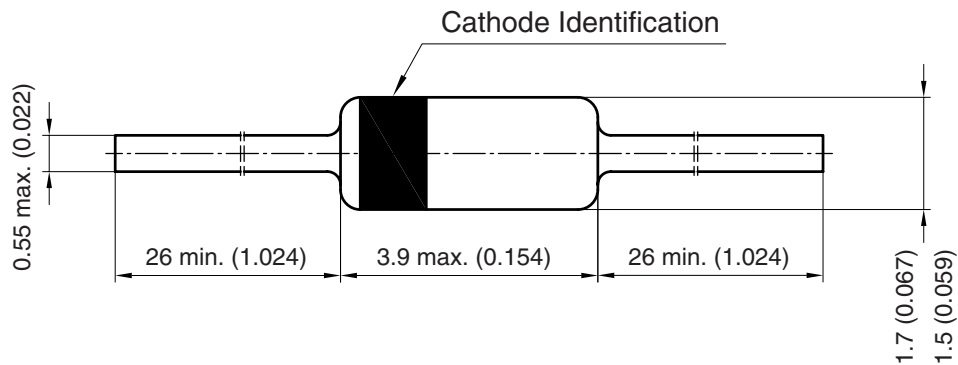
| Parameter | Test condition | Symbol | Value | Unit |
|--|--|------------|---------------|--------------------|
| Thermal resistance junction to ambient air | $l = 4\text{ mm}, T_L = \text{constant}$ | R_{thJA} | 350 | K/W |
| Junction temperature | | T_j | 175 | $^{\circ}\text{C}$ |
| Storage temperature range | | T_{stg} | - 65 to + 175 | $^{\circ}\text{C}$ |

Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
|-----------------------|---|------------|-----|------|------|---------------|
| Forward voltage | $I_F = 10\text{ mA}$ | V_F | | 670 | 750 | mV |
| | $I_F = 50\text{ mA}$ | V_F | | 800 | 850 | mV |
| | $I_F = 200\text{ mA}$ | V_F | | 950 | 1000 | mV |
| | $I_F = 400\text{ mA}$ | V_F | | 1120 | 1250 | mV |
| Reverse current | $V_R = 60\text{ V}$ | I_R | | | 100 | nA |
| | $V_R = 60\text{ V}, T_j = 100\text{ }^{\circ}\text{C}$ | I_R | | | 50 | μA |
| Breakdown voltage | $I_R = 5\text{ }\mu\text{A}, t_p/T = 0.01, t_p = 0.3\text{ ms}$ | $V_{(BR)}$ | 75 | | | V |
| Diode capacitance | $V_R = 0, f = 1\text{ MHz}, V_{HF} = 50\text{ mV}$ | C_D | | | 4 | pF |
| Reverse recovery time | $I_F = I_R = 10\text{ to }100\text{ mA},$ $i_R = 0.1 \times I_R$ | t_{rr} | | | 6 | ns |

Package Dimensions in millimeters (inches): D035



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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
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Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9